

DMOS driver for bipolar stepper motor

Datasheet - production data

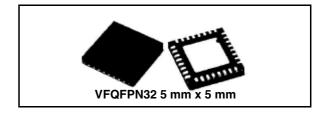
Features

- Operating supply voltage from 8 to 52 V
- 2.8 A output peak current (1.4 A_{r.m.s.})
- R_{DS(on)} 0.73 Ω typ. value @ T_J = 25 °C
- Operating frequency up to 100 kHz
- Non dissipative overcurrent protection
- Dual independent constant t_{OFF} PWM current controllers
- Fast/slow decay mode selection
- Fast decay quasi-synchronous rectification
- Decoding logic for stepper motor full and halfstep drive
- Cross conduction protection
- Thermal shutdown
- Undervoltage lockout
- Integrated fast free wheeling diodes

Applications

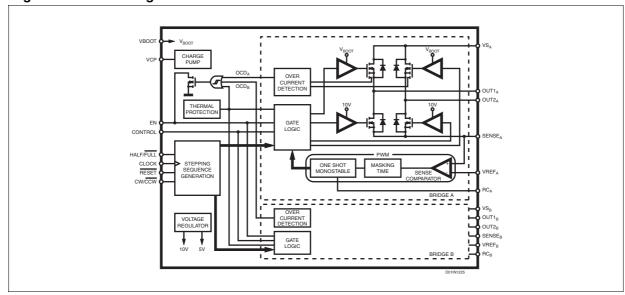
Bipolar stepper motor

Figure 1. Block diagram



Description

The L6228Q is a DMOS fully integrated stepper motor driver with non-dissipative overcurrent protection, realized in BCD multipower technology, which combines isolated DMOS power transistors with CMOS and bipolar circuits on the same chip. The device includes all the circuitry needed to drive a two-phase bipolar stepper motor including: a dual DMOS full-bridge, the constant off-time PWM current controller that performs the chopping regulation and the phase sequence generator, that generates the stepping sequence. Available in VFQFPN32 5 mm x 5 mm package, the L6228Q features a non-dissipative overcurrent protection on the high-side power MOSFETs and thermal shutdown.



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L6228Q Electrical data

1 Electrical data

1.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Parameter	Value	Unit
V _S	Supply voltage	$V_{SA} = V_{SB} = V_{S}$	60	V
V _{OD}	Differential voltage between VS _A , OUT1 _A , OUT2 _A , SENSE _A and VS _B , OUT1 _B , OUT2 _B , SENSE _B	$V_{SA} = V_{SB} = V_{S} = 60 \text{ V};$ $V_{SENSEA} = V_{SENSEB} =$ GND	60	V
V _{BOOT}	Bootstrap peak voltage	$V_{SA} = V_{SB} = V_{S}$	V _S + 10	V
V_{IN}, V_{EN}	Input and enable voltage range		-0.3 to +7	V
V _{REFA} , V _{REFB}	Voltage range at pins V _{REFA} and V _{REFB}		-0.3 to +7	V
V _{RCA} , V _{RCB}	Voltage range at pins RC _A and RC _B		-0.3 to +7	V
V _{SENSEA,} V _{SENSEB}	Voltage range at pins SENSE _A and SENSE _B		-1 to +4	V
I _{S(peak)}	Pulsed supply current (for each V _S pin), internally limited by the overcurrent protection	$V_{SA} = V_{SB} = V_S;$ $t_{PULSE} < 1 \text{ ms}$	3.55	А
I _S	RMS supply current (for each V _S pin)	$V_{SA} = V_{SB} = V_{S}$	1.4	Α
T _{stg} , T _{OP}	Storage and operating temperature range		-40 to 150	°C

1.2 Recommended operating conditions

Table 2. Recommended operating conditions

Symbol	Parameter	Parameter	Min.	Max.	Unit
V _S	Supply voltage	$V_{SA} = V_{SB} = V_{S}$	8	52	V
V _{OD}	Differential voltage between VS _A , OUT1 _A , OUT2 _A , SENSE _A and VS _B , OUT1 _B , OUT2 _B , SENSE _B	V _{SA} = V _{SB} = V _S ; V _{SENSEA} = V _{SENSEB}		52	V
V _{REFA} , V _{REFB}	Voltage range at pins V _{REFA} and V _{REFB}		-0.1	5	V
V _{SENSEA} , V _{SENSEB}	Voltage range at pins SENSE _A and SENSE _B	(pulsed t _W < t _{rr}) (DC)	-6 -1	6 1	V V
I _{OUT}	RMS output current			1.4	Α
f _{sw}	Switching frequency			100	kHz

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1.3 Thermal data

Table 3. Thermal data

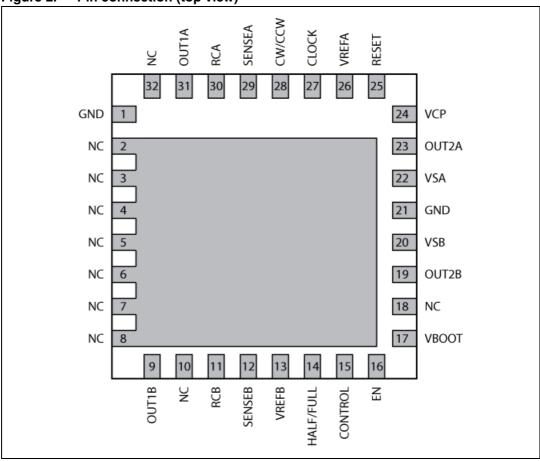
Symbol	Parameter	Value	Unit
R _{th(JA)}	Thermal resistance junction-ambient max (1)	42	° C/W

Mounted on a double-layer FR4 PCB with a dissipating copper surface of 0.5 cm² on the top side plus 6 cm² ground layer connected through 18 via holes (9 below the IC).

L6228Q Pin connection

2 Pin connection

Figure 2. Pin connection (top view)



Note: 1 The pins from 2 to 8 are connected to die PAD.

2 The die PAD must be connected to GND pin.

Pin connection L6228Q

Table 4. Pin description

N°	Pin	Туре	Function	
	GND	GND	Ground terminals	
1, 21		_		
9	OUT1 _B	Power output	Bridge B output 1	
11	RC _B	RC pin	RC network pin. A parallel RC network connected between this pin and ground sets the current controller off-time of the bridge B.	
12	SENSEB	Power supply	Bridge B source pin. This pin must be connected to power ground through a sensing power resistor.	
13	VREFB	Analog input	Bridge B current controller reference voltage. Do not leave this pin open or connected to GND.	
14	HALF/FULL	Logic input	Step mode selector. HIGH logic level sets HALF-STEP mode, LOW logic level sets FULL-STEP mode. If not used, it has to be connected to GND or + 5 V.	
			Decay mode selector. HIGH logic level sets SLOW DECAY mode. LOW logic	
15	CONTROL	Logic input	level sets FAST DECAY mode.	
		5 1	If not used, it has to be connected to GND or + 5 V.	
16	EN	Logic input ⁽¹⁾	Chip enable. LOW logic level switches OFF all power MOSFETs of both bridge A and bridge B. This pin is also connected to the collector of the overcurrent and thermal protection to implement overcurrent protection. If not used, it has to be connected to +5 V through a resistor.	
17	VBOOT	Supply voltage	Bootstrap voltage needed to drive the upper power MOSFETs of both bridge A and bridge B.	
19	OUT2 _B	Power output	Bridge B output 2.	
20	VS _B	Power supply	Bridge B power supply voltage. It must be connected to the supply voltage together with pin ${\sf VS}_{\sf A}$	
22	VS _A	Power supply	Bridge A power supply voltage. It must be connected to the supply voltage together with pin ${\sf VS}_{\sf B}$	
23	OUT2 _A	Power output	Bridge A output 2.	
24	VCP	Output	Charge pump oscillator output.	
25	RESET	Logic input	Reset pin. LOW logic level restores the home state (state 1) on the phase sequence generator state machine. If not used, it has to be connected to +5 V.	
26	VREF _A	Analog Input	Bridge A current controller reference voltage. Do not leave this pin open or connected to GND.	
27	CLOCK	Logic input	Step clock input. The state machine makes one step on each rising edge.	
28	CW/CCW	Logic input	Selects the direction of the rotation. HIGH logic level sets clockwise direction, whereas LOW logic level sets counterclockwise direction. If not used, it has to be connected to GND or +5 V.	
29	SENSEA	Power supply	Bridge A source pin. This pin must be connected to power ground through a sensing power resistor.	
30	RC _A	RC pin	RC network pin. A parallel RC network connected between this pin and ground sets the current controller off-time of the bridge A.	
31	OUT1 _A	Power output	Bridge A output 1	

^{1.} Also connected to the output drain of the overcurrent and thermal protection MOSFET. Therefore, it has to be driven putting in series a resistor with a value in the range from 2.2 k Ω to 180 k Ω , recommended 100 k Ω

3 Electrical characteristics

Table 5.Electrical characteristics ($T_A = 25$ °C, $V_S = 48$ V, unless otherwise specified)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _{Sth(ON)}	Turn-on threshold		5.8	6.3	6.8	V
V _{Sth(OFF)}	Turn-off threshold		5	5.5	6	V
I _S	Quiescent supply current	All bridges OFF; $T_J = -25 ^{\circ}\text{C to } 125 ^{\circ}\text{C}^{(1)}$		5	10	mA
T _{j(OFF)}	Thermal shutdown temperature			165		°C
Output DM	OS transistors	•	•			
В	High-side + low-side switch ON	T _J = 25 ° C		1.47	1.69	Ω
R _{DS(on)}	resistance	T _J =125 °C ⁽¹⁾		2.35	2.70	Ω
	Lockogo current	EN = Low; OUT = V _S			2	mA
I _{DSS}	Leakage current	EN = Low; OUT = GND	-0.3			mA
Source drai	in diodes	•				
V _{SD}	Forward ON voltage	I _{SD} = 1.4 A, EN = LOW		1.15	1.3	٧
t _{rr}	Reverse recovery time	I _f = 1.4 A		300		ns
t _{fr}	Forward recovery time			200		ns
Logic input	s (EN, CONTROL, HALF/FULL, CLOCK	K, RESET, CW/CCW)	•			
V _{IL}	Low level logic input voltage		-0.3		0.8	V
V _{IH}	High level logic input voltage		2		7	V
I _{IL}	Low level logic input current	GND logic input voltage	-10			μΑ
I _{IH}	High level logic input current	7 V logic input voltage			10	μΑ
V _{th(ON)}	Turn-on input threshold			1.8	2.0	V
V _{th(OFF)}	Turn-off input threshold		0.8	1.3		V
V _{th(HYS)}	Input threshold hysteresis		0.25	0.5		٧
Switching of	characteristics	•				
t _{D(ON)EN}	Enable to output turn-on delay time ⁽²⁾		500	650	800	ns
t _{D(OFF)EN}	Enable to output turn-off delay time ⁽²⁾		500	800	1000	ns
t _{RISE}	Output rise time ⁽²⁾	I _{LOAD} =1.4 A, resistive load	40		250	ns
t _{FALL}	Output fall time ⁽²⁾		40		250	ns
t _{DCLK}	Clock to output delay time (3)			2		μs
t _{CLK(min)L}	Minimum clock time ⁽⁴⁾				1	μs
t _{CLK(min)H}	Minimum clock time ⁽⁴⁾				1	μs
f _{CLK}	Clock frequency				100	kHz

Electrical characteristics L6228Q

Table 5.Electrical characteristics (continued) ($T_A = 25$ °C, Vs = 48 V, unless otherwise specified)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
t _{S(MIN)}	Minimum set-up time ⁽⁵⁾				1	μs
t _{H(MIN)}	Minimum hold time ⁽⁵⁾				1	μs
t _{R(MIN)}	Minimum reset time ⁽⁵⁾				1	μs
t _{RCLK(MIN)}	Minimum reset to clock delay time ⁽⁵⁾				1	μs
t _{DT}	Dead time protection		0.5	1		μs
f _{CP}	Charge pump frequency	$T_{J} = -25 ^{\circ}\text{C} \text{ to } 125 ^{\circ}\text{C} ^{(1)}$		0.6	1	MHz
PWM comp	arator and monostable					
I _{RCA,} I _{RCB}	Source current at pins RC _A and RC _B	V _{RCA} = V _{RCB} = 2.5 V	3.5	5.5		mA
V _{offset}	Offset voltage on sense comparator	V _{REFA} , V _{REFB} = 0.5 V		±5		mV
t _{PROP}	Turn-OFF propagation delay ⁽⁶⁾			500		ns
t _{BLANK}	Internal blanking time on SENSE pins			1		μs
t _{ON(MIN)}	Minimum on time			2.5	3	μs
+	PWM recirculation time	$R_{OFF} = 20 \text{ k}\Omega; C_{OFF} = 1 \text{ nF}$		13		μs
t _{OFF}	P VVIVI Techculation time	$R_{OFF} = 100 \text{ k}\Omega; C_{OFF} = 1 \text{ nF}$		61		μs
I _{BIAS}	Input bias current at pins $VREF_A$ and $VREF_B$				10	μΑ
Over currer	nt protection					
I _{SOVER}	Input supply overcurrent protection threshold	$T_j = -25 ^{\circ}\text{C to } 125 ^{\circ}\text{C} ^{(1)}$		2.8		Α
R _{OPDR}	Open drain ON resistance	I = 4 mA		40	60	W
t _{OCD(ON)}	OCD turn-ON delay time ⁽⁷⁾	I = 4 mA; C _{EN} < 100 pF		200		ns
t _{OCD(OFF)}	OCD turn-OFF delay time ⁽⁷⁾	I = 4 mA; C _{EN} < 100 pF		100		ns

^{1.} Tested at 25 $^{\circ}\text{C}$ in a restricted range and guaranteed by characterization.

^{2.} See Figure 3.

^{3.} See Figure 4.

^{4.} See Figure 5.

^{5.} See Figure 6.

^{6.} Applying a voltage of 1 V to pin SENSE and a voltage drop from 2 V to 0 V to pin VREF.

^{7.} See Figure 7.

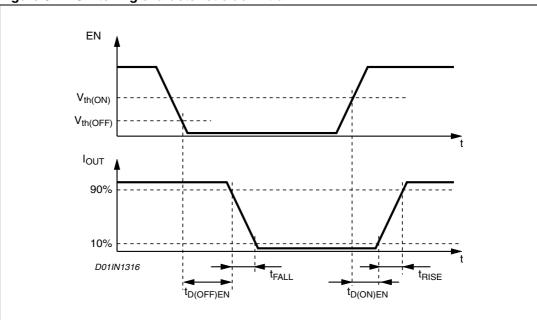
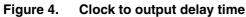
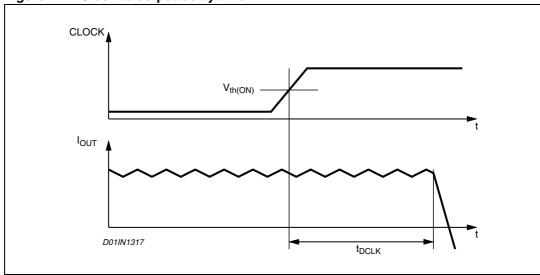


Figure 3. Switching characteristic definition





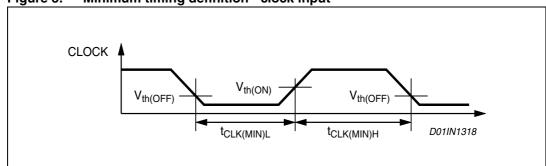


Figure 5. Minimum timing definition - clock input

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Electrical characteristics L6228Q

CLOCK

Vth(ON)

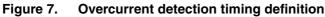
LOGIC INPUTS

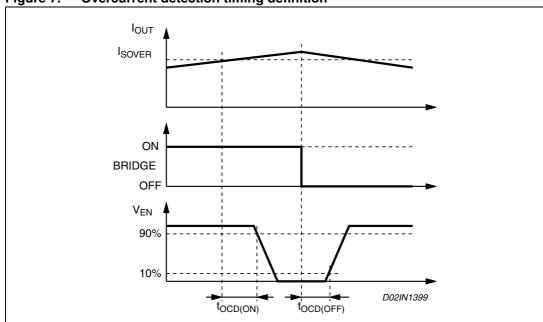
t_{S(MIN)}

t_{H(MIN)}

D01IN1319

Figure 6. Minimum timing definition - logic inputs





L6228Q Circuit description

4 Circuit description

4.1 Power stages and charge pump

The L6228Q integrates two independent power MOSFET full-bridges. Each power MOSFET has an $R_{DS(on)}=0.73~\Omega$ (typical value @ 25 °C), with intrinsic fast freewheeling diode. Switching patterns are generated by the PWM current controller and the phase sequence generator (see below). Cross conduction protection is achieved using a dead time ($t_{\rm DT}=1~\mu \rm s$ typical value) between the switch off and switch on of two power MOSFETs in one leg of a bridge.

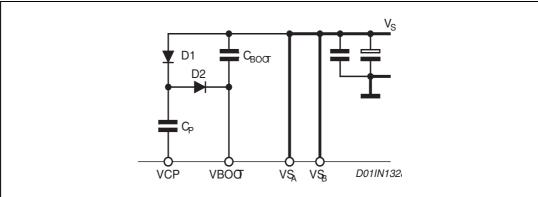
 VS_A and VS_B pins must be connected together to the supply voltage V_S . The device operates with a supply voltage in the range from 8 V to 52 V. It has to be noticed that the $R_{DS(on)}$ increases of some percents when the supply voltage is in the range from 8 V to 12 V

Using N-channel power MOSFETs for the upper transistors in the bridge requires a gate drive voltage above the power supply voltage. The bootstrapped supply voltage V_{BOOT} is obtained through an internal oscillator and few external components to realize a charge pump circuit as shown in *Figure 8*. The oscillator output (VCP) is a square wave at 600 kHz (typical) with 10 V amplitude. Recommended values/part numbers for the charge pump circuit are shown in *Table 6*.

Table 6. Charge pump external component values

Component	Value
C _{BOOT}	220 nF
C _P	10 nF
D1	1N4148
D2	1N4148





Circuit description L6228Q

4.2 Logic inputs

Pins CONTROL, HALF/FULL, CLOCK, RESET and CW/CCW are TTL/CMOS and microcontroller compatible logic inputs. The internal structure is shown in *Figure 9*. Turn-on and turn-off threshold typical values are respectively $V_{th(ON)}$ = 1.8 V and $V_{th(OFF)}$ = 1.3 V.

Pin EN (Enable) has identical input structure with the exception that the drain of the overcurrent and thermal protection MOSFET is also connected to this pin. Due to this connection, this pin has to be driven carefully. The EN input may be driven in one of two configurations as shown in *Figure 10* or *Figure 11*. If driven by an open drain (collector) structure, a pull-up resistor R_{EN} and a capacitor C_{EN} are connected as shown in *Figure 10*. If the driver is a standard Push-Pull structure the resistor R_{EN} and the capacitor C_{EN} are connected as shown in *Figure 11*. The resistor R_{EN} should be chosen in the range from 2.2 $k\Omega$ to 180 $k\Omega$ R_{EN} and C_{EN} recommended values are respectively 100 $k\Omega$ and 5.6 nF.

Figure 9. Logic input internal structure

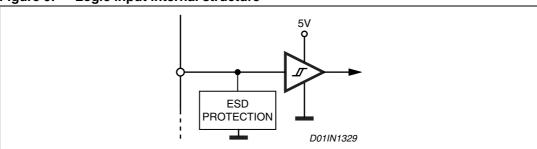


Figure 10. EN pin open collector driving

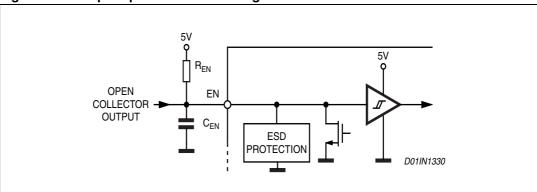
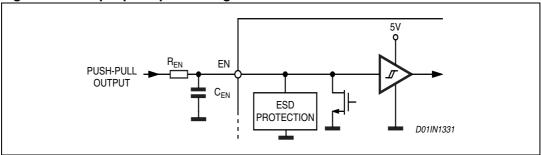


Figure 11. EN pin push-pull driving



L6228Q Circuit description

4.3 PWM current control

The L6228Q includes a constant off-time PWM current controller for each of the two bridges. The current control circuit senses the bridge current, by monitoring the voltage drop across an external sense resistor connected between the source of the two lower power MOSFET transistors and ground, as shown in *Figure 12*. As the current in the motor builds up the voltage across the sense resistor increases proportionally. When the voltage drop across, the sense resistor becomes greater than the voltage at the reference input (VREF_A or VREF_B) the sense comparator triggers the monostable switching the bridge off. The power MOSFETs remain off for the time set by the monostable and the motor current recirculates as defined by the selected decay mode, described in the next section. When the monostable times out, the bridge turns on again. Since the internal dead time, used to prevent cross conduction in the bridge, delays the turn-on of the power MOSFET, the effective off-time is the sum of the monostable time plus the dead time.

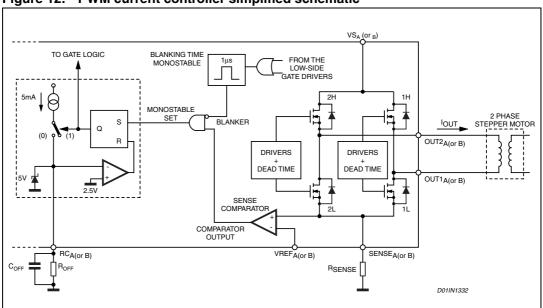


Figure 12. PWM current controller simplified schematic

Figure 13 shows the typical operating waveforms of the output current, the voltage drop across the sensing resistor, the RC pin voltage and the status of the bridge. More details regarding the synchronous rectification and the output stage configuration are included in the next section.

Immediately after the power MOSFET turns on, a high peak current flows through the sensing resistor due to the reverse recovery of the freewheeling diodes. The L6228Q provides a 1 μ s blanking time t_{BLANK} that inhibits the comparator output so that this current spike cannot prematurely re-trigger the monostable.

Circuit description L6228Q

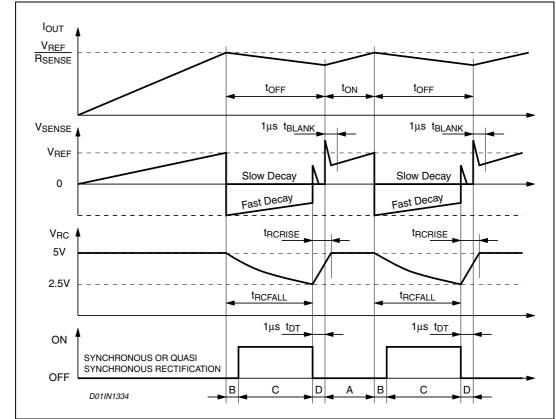


Figure 13. Output current regulation waveforms

Figure 14 shows the magnitude of the off-time t_{OFF} versus C_{OFF} and R_{OFF} values. It can be approximately calculated from the equations:

$$\begin{aligned} t_{RCFALL} &= 0.6 \cdot R_{OFF} \cdot C_{OFF} \\ t_{OFF} &= t_{RCFALL} + t_{DT} = 0.6 \cdot R_{OFF} \cdot C_{OFF} + t_{DT} \end{aligned}$$

where R_{OFF} and C_{OFF} are the external component values and t_{DT} is the internally generated Dead Time with:

20 k
$$\Omega \le R_{OFF} \le 100 \text{ k}\Omega$$

0.47 nF $\le C_{OFF} \le 100 \text{ nF}$
 $t_{DT} = 1 \mu \text{s}$ (typical value)

Therefore:

 $t_{OFF(MIN)} = 6.6 \mu s$ $t_{OFF(MAX)} = 6 ms$

These values allow a sufficient range of t_{OFF} to implement the drive circuit for most motors.

The capacitor value chosen for C_{OFF} also affects the rise time t_{RCRISE} of the voltage at the pin RCOFF. The rise time t_{RCRISE} can be an issue if the capacitor is not completely charged before than the next time the monostable is triggered. Therefore, the on time t_{ON} , which depends on motors and supply parameters, has to be bigger than t_{RCRISE} to allow a good current regulation by the PWM stage. Furthermore, the on time t_{ON} can not be smaller than the minimum on time $t_{ON(MIN)}$.

L6228Q Circuit description

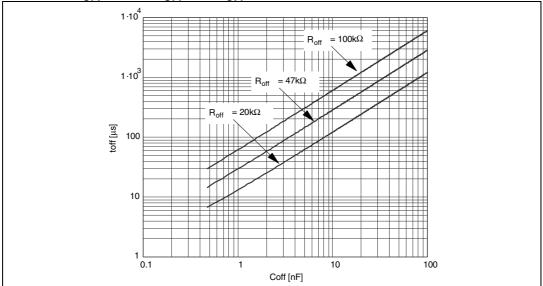
$$\begin{cases} t_{\text{ON}} > t_{\text{ON(MIN)}} = 2.5 \mu \text{s} & \text{(typ. value)} \\ t_{\text{ON}} > t_{\text{RCRISE}} - t_{\text{DT}} & \text{(typ. value)} \end{cases}$$

 $t_{RCRISE} = 600 \cdot C_{OFF}$

Figure 15 shows the lower limit for the on time t_{ON} to get a good PWM current regulation capacity. It has to be said that t_{ON} is always bigger than $t_{ON(MIN)}$ because the device imposes this condition, but it can be smaller than t_{RCRISE} - t_{DT} . In this last case the device continues working but the off-time t_{OFF} is not more constant.

So, small C_{OFF} value gives more flexibility for the applications (allows smaller on time and, therefore, higher switching frequency), but, the smaller the value for C_{OFF} the more influential the noises on the circuit performance.





Circuit description L6228Q

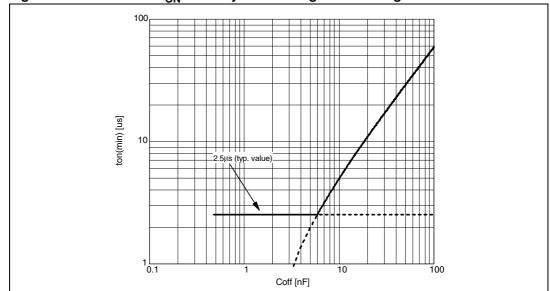


Figure 15. Area where $t_{\mbox{\scriptsize ON}}$ can vary maintaining the PWM regulation

4.4 Decay modes

The CONTROL input is used to select the behavior of the bridge during the off-time. When the CONTROL pin is low, the fast decay mode is selected and both transistors in the bridge are switched off during the off-time. When the CONTROL pin is high, the slow decay mode is selected and only the low-side transistor of the bridge is switched off during the off-time.

Figure 16 shows the operation of the bridge in the fast decay mode. At the start of the off-time, both of the power MOSFETs are switched off and the current recirculates through the two opposite free wheeling diodes. The current decays with a high dl/dt since the voltage across the coil is essentially the power supply voltage. After the dead time, the lower power MOSFET, in parallel with the conducting diode, is turned on in synchronous rectification mode. In applications where the motor current is low, it is possible for the current to decay completely to zero during the off-time. At this point, if both of the power MOSFETs were operating in the synchronous rectification mode it would be possible for the current to build in the opposite direction. To prevent this, the lower power MOSFET is operated in synchronous rectification mode only. This operation is called quasi-synchronous rectification mode. When the monostable times out, the power MOSFETs are turned on again after some delay set by the dead time to prevent cross conduction.

Figure 17 shows the operation of the bridge in the slow decay mode. At the start of the off-time, the lower power MOSFET is switched off and the current recirculates around the upper half of the bridge. Since the voltage across the coil is low, the current decays slowly. After the dead time, the upper power MOSFET is operated in the synchronous rectification mode. When the monostable times out, the lower power MOSFET is turned on again after some delay set by the dead time to prevent cross conduction.

L6228Q Circuit description

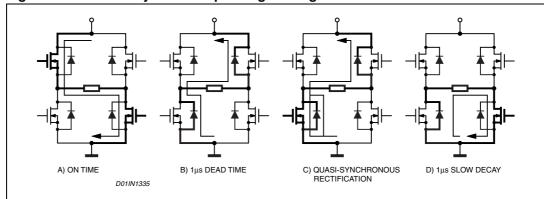
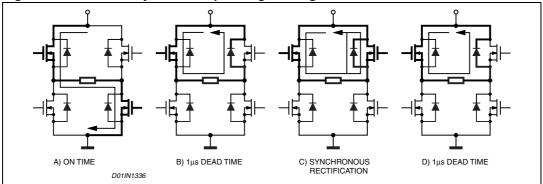


Figure 16. Fast decay mode output stage configurations

Figure 17. Slow decay mode output stage configurations



4.5 Stepping sequence generation

The phase sequence generator is a state machine that provides the phase and enable inputs for the two bridges to drive a stepper motor in either full-step or half-step. Two full-step modes are possible, the normal drive mode where both phases are energized each step and the wave drive mode where only one phase is energized at a time. The drive mode is selected by the HALF/FULL input and the current state of the sequence generator as described below. A rising edge of the CLOCK input advances the state machine to the next state. The direction of rotation is set by the CW/CCW input. The RESET input resets the state machine to state 1.

4.5.1 Half-step mode

A high logic level on the HALF/FULL input selects half-step mode. *Figure 18* shows the motor current waveforms and the state diagram for the phase sequencer generator. At startup or after a RESET the phase sequencer is at state 1. After each clock pulse the state changes following the sequence 1,2,3,4,5,6,7,8,... if CW/CCW is high (clockwise movement) or 1,8,7,6,5,4,3,2,... if CW/CCW is low (counterclockwise movement).

Circuit description L6228Q

4.5.2 Normal drive mode (full-step two-phase-on)

A low level on the HALF/FULL input selects the full-step mode. The normal drive mode is selected if the low level is applied when the state machine is at an ODD state. *Figure 19* shows the motor current waveform state diagram for the state machine of the phase sequencer generator. The normal drive mode can easily be selected by holding the HALF/FULL input low and applying a RESET. At startup or after a RESET the state machine is in state 1. While the HALF/FULL input is kept low, the state changes following the sequence 1,3,5,7,... if CW/CCW is high (clockwise movement) or 1,7,5,3,... if CW/CCW is low (counterclockwise movement).

4.5.3 Wave drive mode (full-step one-phase-on)

A low level on the pin HALF/FULL input selects the full-step mode. The wave drive mode is selected if the low level is applied when the state machine is at an EVEN state. *Figure 20* shows the motor current waveform and the state diagram for the state machine of the phase sequence generator. To enter the wave drive mode, the state machine must be in an EVEN numbered state. The most direct method to select the wave drive mode is to apply a RESET first, then while keeping the HALF/FULL input high, applying one pulse to the clock input, then taking the HALF/FULL input low. This sequence forces the state machine to state 1. The clock pulse, with the HALF/FULL input high, advances the state machine from state 1 to either state 2 or 8 depending on the CW/CCW input. Starting from this point, after each clock pulse (rising edge) advances the state machine following the sequence 2,4,6,8,... if CW/CCW is high (clockwise movement) or 8,6,4,2,... if CW/CCW is low (counterclockwise movement).

Figure 18. Half-step mode

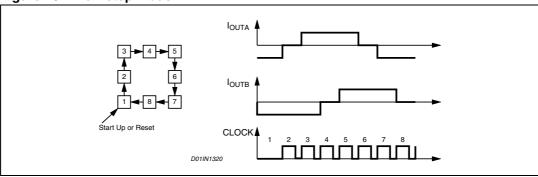
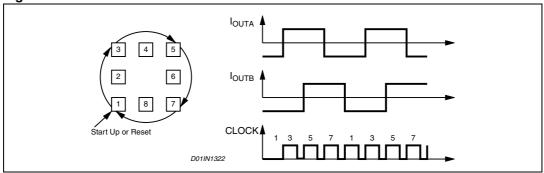
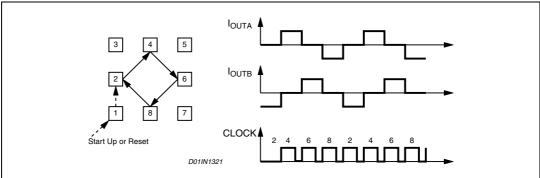


Figure 19. Normal drive mode



L6228Q Circuit description

Figure 20. Wave drive mode



4.6 Non-dissipative overcurrent protection

The L6228Q integrates an overcurrent detection circuit (OCD) for full protection. This circuit provides protection against a short-circuit to ground or between two phases of the bridge. With this internal overcurrent detection, the external current sense resistor normally used and its associated power dissipation are eliminated. *Figure 21* shows a simplified schematic of the overcurrent detection circuit.

To implement the overcurrent detection, a sensing element delivering a small but precise fraction of each high-side MOSFET current is integrated. Since this current is a small fraction of the output current there is very little additional power dissipation. This current is compared with an internal reference current I_{REF} When the output current reaches the detection threshold (typically 2.8 A) the OCD comparator signals a fault condition. When a fault condition is detected, the EN pin is pulled below the turn-off threshold (1.3 V typical) by an internal open drain MOSFET with a pull down capability of 4 mA. By using an external R-C on the EN pin, the off-time before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs.

Circuit description L6228Q

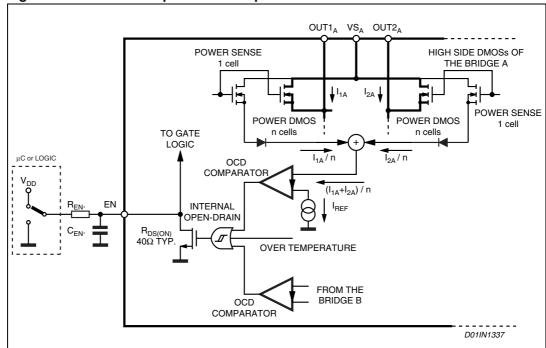


Figure 21. Overcurrent protection simplified schematic

Figure 22 shows the overcurrent detection operation. The disable time $t_{DISABLE}$ before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs. It is affected both by C_{EN} and R_{EN} values and its magnitude is reported in Figure 23. The delay time t_{DELAY} before turning off the bridge when an overcurrent has been detected depends only by C_{EN} value. Its magnitude is reported in Figure 24.

 C_{EN} is also used to provide immunity to pin EN against fast transient noises. Therefore the value of C_{EN} should be chosen as big as possible according to the maximum tolerable delay time and the R_{EN} value should be chosen according to the desired disable time.

The resistor R_{EN} should be chosen in the range from 2.2 k Ω to 180 k Ω Recommended values for R_{EN} and C_{EN} are respectively 100 k Ω and 5.6 nF that allow 200 μ s disable time to be obtained.

L6228Q Circuit description

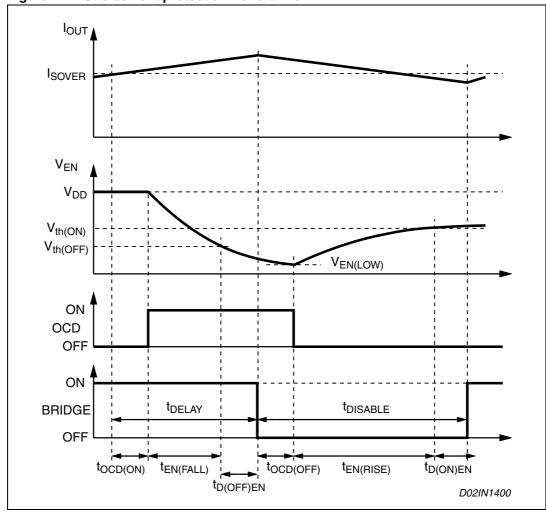


Figure 22. Overcurrent protection waveforms

Circuit description L6228Q

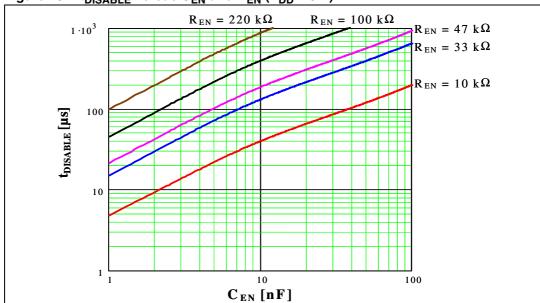
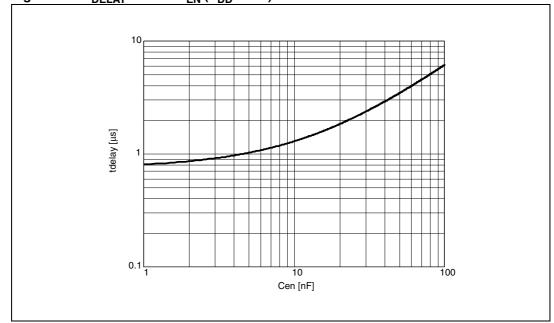


Figure 23. $t_{DISABLE}$ versus C_{EN} and R_{EN} ($V_{DD} = 5 V$)





4.7 Thermal protection

In addition to the overcurrent protection, the L6228Q integrates a thermal protection to prevent the device destruction in case of junction overtemperature. It senses the die temperature by means of a sensible element integrated in the die. The device switches off when the junction temperature reaches 165 $^{\circ}$ C (typ. value) with 15 $^{\circ}$ C hysteresis (typ. value).

5 Application information

A typical bipolar stepper motor driver application using L6228Q is shown in *Figure 25*. Typical component values for the application are shown in *Table 7*. A high quality ceramic capacitor in the range from 100 to 200 nF should be placed between the power pins (VS_A and VS_B) and ground near the L6228Q to improve the high frequency filtering on the power supply and to reduce high frequency transients generated by the switching. The capacitor connected from the EN input to ground sets the shut down time when an overcurrent is detected (see overcurrent protection). The two current sensing inputs (SENSE_A and SENSE_B) should be connected to the sensing resistors with a trace length as short as possible in the layout. The sense resistors should be non-inductive resistors to minimize the dl/dt transients across the resistor. To increase noise immunity, unused logic pins (except EN) are connected to 5 V (high logic level) or GND (low logic level) (see pin description). It is recommended power ground and signal ground to be separated on PCB.

Table 7. Component values for typical application

Component	Value
C ₁	100 μF
C ₂	100 nF
C _A	1 nF
C _B	1 nF
C _{BOOT}	220 nF
C _P	10 nF
C _{EN}	5.6 nF
C _{REF}	68 nF
D ₁	1N4148
D ₂	1N4148
R _A	39 kΩ
R _B	39 kΩ
R _{EN}	100 kΩ
R _{SENSEA}	0.6 Ω
R _{SENSEB}	0.6 Ω

O ¥ I GND 24 2 NC OUT2A D₂ D1 3 VSA GND 21 **1**(M) VSB SIGNAL GROUND OUT2B Cboot GROUND HALF/FULL CONTROL 8 NC Ä ENABLE

Figure 25. Typical application

Note:

To reduce the IC thermal resistance, so to improve the dissipation path, the NC pins can be connected to GND.

6 Output current capability and IC power dissipation

The approximate relation between the output current and the IC power dissipation using PWM current control driving a two-phase stepper motor, for different driving sequences (see *Figure 26*, *Figure 27*, *Figure 28* and *Figure 29*):

- HALF-STEP mode (Figure 26) in which alternately one phase/two phases are energized.
- NORMAL DRIVE (FULL-STEP TWO PHASE ON) mode (Figure 27) in which two phases are energized during each step.
- WAVE DRIVE (FULL-STEP ONE PHASE ON) mode (Figure 27) in which only one phase is energized at each step.
- MICROSTEPPING mode (*Figure 29*), in which the current follows a sine wave profile, provided through the V_{ref} pins.

For a given output current and driving sequence, the power dissipated by the IC can be easily evaluated, in order to establish which package should be used and how large the onboard copper dissipating area must be to guarantee a safe operating junction temperature (125 °C maximum).

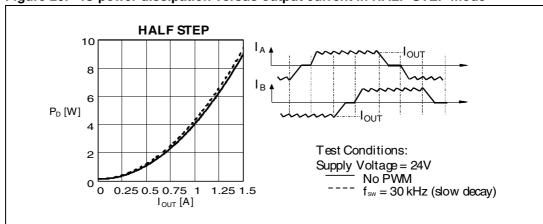


Figure 26. IC power dissipation versus output current in HALF-STEP mode

NORM AL DRIVE

10

8

6

P_D [W]

4

2

0

0

0.25 0.5 0.75 1 1.25 1.5

I_{OUT} [A]

1

NORM AL DRIVE

1

I_B

Test Conditions:
Supply Voltage = 24 V

No PWM

---- f_{SW} = 30 kHz (slow decay)

Figure 27. IC power dissipation versus output current in NORMAL mode (full-step-two-phase on)

Figure 28. IC power dissipation versus output current in WAVE mode (full-step-one phase-on)

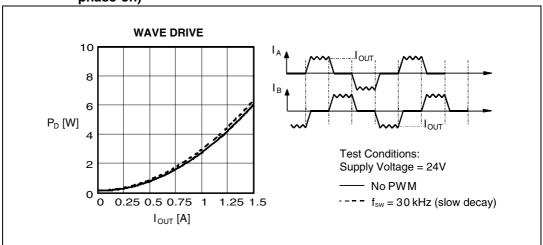
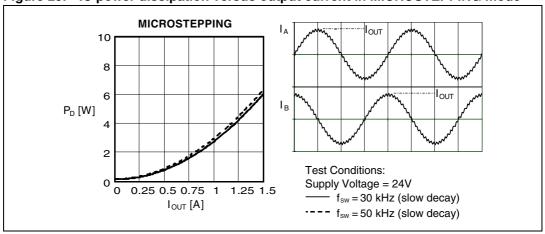


Figure 29. IC power dissipation versus output current in MICROSTEPPING mode



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7 Thermal management

In most applications the power dissipation in the IC is the main factor that sets the maximum current that can be delivered by the device in a safe operating condition. Therefore, it has to be taken into account very carefully. Besides, the available space on the PCB, the right package should be chosen considering the power dissipation. Heat sinking can be achieved using copper on the PCB with proper area and thickness.

For instance, using a VFQFPN32L 5x5 package the typical $R_{th(JA)}$ is about 42 °C/W when mounted on a double-layer FR4 PCB with a dissipating copper surface of 0.5 cm² on the top side plus 6 cm² ground layer connected through 18 via holes (9 below the IC).

8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 8. VFQFPN32 5x5x1.0 pitch 0.50

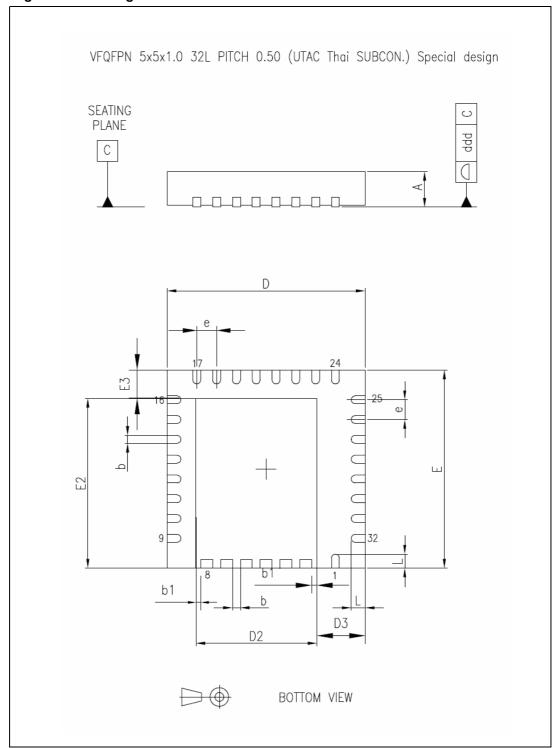
Dim	mm				
Dim.	Min.	Тур.	Max.		
А	0.80	0.85	0.95		
b	0.18	0.25	0.30		
b1	0.165	0.175	0.185		
D	4.85	5.00	5.15		
D2	3.00	3.10	3.20		
D3	1.10	1.20	1.30		
E	4.85	5.00	5.15		
E2	4.20	4.30	4.40		
E3	0.60	0.70	0.80		
е		0.50			
L	0.30	0.40	0.50		
ddd			0.08		

Note:

VFQFPN stands for thermally enhanced very thin profile fine pitch quad flat package no lead. Very thin profile: 0.80 < A < 1.00 mm.

Details of terminal 1 are optional but must be located on the top surface of the package by using either a mold or marked features.

Figure 30. Package dimensions



Ordering information L6228Q

9 Ordering information

Table 9. Ordering information

Order code	Package	Packaging	
L6228Q	VFQFPN32 5x5x1.0 mm	Tube	
L6228QTR	VI QIT NOZ SXSXI.O IIIIII	Tape and reel	

L6228Q Revision history

10 Revision history

Table 10. Document revision history

Date	Revision	Changes
14-Jan-2008	1	First release.
10-Jun-2008	2	Updated: Figure 25 on page 24 Added: Note 1 on page 4
28-Jan-2009	3	Updated value in Table 3: Thermal data on page 4
31-Aug-2010	4	Updated Table 9
28-Jan-2013	5	Updated <i>Table 2</i> . Minor text changes.

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